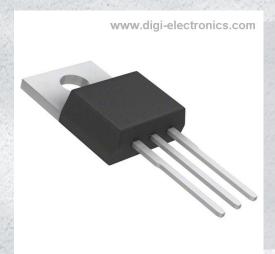


FQP13N06L Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number FQP13N06L-DG

Manufacturer onsemi

Manufacturer Product Number FQP13N06L

Description MOSFET N-CH 60V 13.6A TO220-3

Detailed Description N-Channel 60 V 13.6A (Tc) 45W (Tc) Through Hole T

0-220-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FQP13N06L	onsemi
Series:	Product Status:
QFET®	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
60 V	13.6A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
5V, 10V	110mOhm @ 6.8A, 10V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
2.5V @ 250μA	6.4 nC @ 5 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	350 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	45W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 175°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-220-3	TO-220-3
Base Product Number:	
FOP13	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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November 2013

FQP13N06L

N-Channel QFET[®] MOSFET 60 V, 13.6 A, 110 m Ω

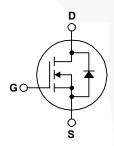
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 13.6 A, 60 V, $R_{DS(on)}$ = 110 m Ω (Max.) @ V_{GS} = 10 V, I_{D} = 6.8 A
- Low Gate Charge (Typ. 4.8 nC)
- Low Crss (Typ. 17 pF)
- · 100% Avalanche Tested
- · 175°C Maximum Junction Temperature Rating





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQP13N06L	Unit
V _{DSS}	Drain-Source Voltage		60	V
I _D	Drain Current - Continuous (T _C = 25°	C)	13.6	Α
	- Continuous (T _C = 100)°C)	9.6	А
I _{DM}	Drain Current - Pulsed	(Note 1)	54.4	Α
V _{GSS}	Gate-Source Voltage		± 20	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	90	mJ
I _{AR}	Avalanche Current	(Note 1)	13.6	A
E _{AR}	Repetitive Avalanche Energy	(Note 1)	4.5	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		7.0	V/ns
P_{D}	Power Dissipation (T _C = 25°C)		45	W
	- Derate above 25°C		0.3	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 seconds		300	°C

Thermal Characteristics

Symbol	Parameter	FQP13N06L	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	3.35	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQP13N06L	FQP13N06L	TO-220	Tube	N/A	N/A	50 units

Fle	ctrical	l Chara	cter	istics
	Cuica	ı Cılala	CLEI	SHE

T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions		Min	Тур	Max	Uni
Off Cha	aracteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		60			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced	to 25°C		0.05		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 60 V, V _{GS} = 0 V				1	μΑ
	Zero Gate voltage Drain Current	V _{DS} = 48 V, T _C = 150°C				10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 20 V, V _{DS} = 0 V				100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$				-100	nA
On Cha	aracteristics		(
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1	1.0		2.5	V
R _{DS(on)}	Static Drain-Source	$V_{GS} = 10 \text{ V}, I_D = 6.8 \text{ A}$			0.088	0.11	Ω
	On-Resistance $V_{GS} = 5 \text{ V}, I_D = 6.8 \text{ A}$				0.110	0.14	
9 _{FS}	Forward Transconductance	$V_{DS} = 25 \text{ V}, I_{D} = 6.8 \text{ A}$			7		S
Dynam	ic Characteristics						
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,			270	350	pF
Coss	Output Capacitance	f = 1.0 MHz			95	125	pF
C _{rss}	Reverse Transfer Capacitance				17	23	pF
Switchi	ing Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{DD} = 30 V, I _D = 6.8 A,			8	25	ns
t _r	Turn-On Rise Time $R_G = 25 \Omega$			90	190	ns	
$t_{d(off)}$	Turn-Off Delay Time	S			20	50	ns
t _f	Turn-Off Fall Time		(Note 4)	/	40	90	ns
Q_g	Total Gate Charge	V _{DS} = 48 V, I _D = 13.6 A,			4.8	6.4	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 5 V (Note 4)			1.6		nC
Q _{gd}							

Drain-Source Diode Characteristics and Maximum Ratings

I_S	Maximum Continuous Drain-Source Diode Forward Current		 	13.6	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current		 	54.4	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 13.6 A	 	1.5	V
t _{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{S} = 13.6 \text{ A},$	 45		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs	 45		nC

- **Notes:** 1. Repetitive Rating : Pulse width limited by maximum junction temperature. 2. L = 570 μ H, I_{AS} = 13.6 A, V_{DD} = 25 V, R_G = 25 Ω , starting T_J = 25°C. 3. I_{SD} \leq 13.6 A, di/dt \leq 300 A/ μ s, V_{DD} \leq BV_{DSS}, starting T_J = 25°C. 4. Essentially independent of operating temperature.

Typical Characteristics

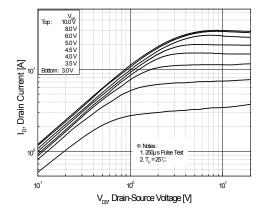


Figure 1. On-Region Characteristics

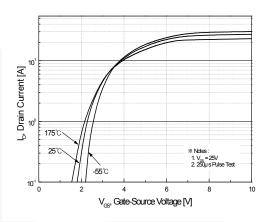


Figure 2. Transfer Characteristics

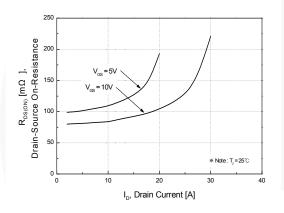


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

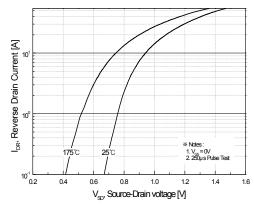


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

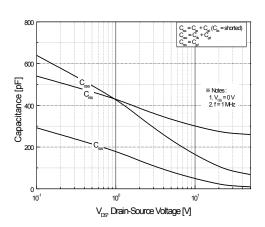


Figure 5. Capacitance Characteristics

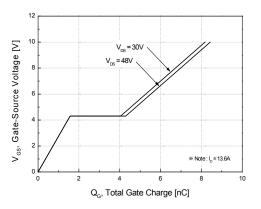


Figure 6. Gate Charge Characteristics



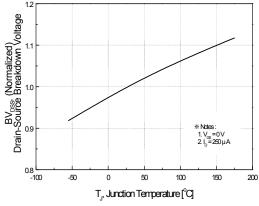


Figure 7. Breakdown Voltage Variation vs. Temperature

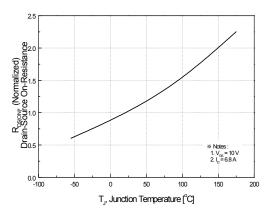


Figure 8. On-Resistance Variation vs. Temperature

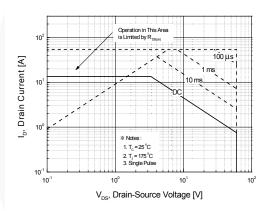


Figure 9. Maximum Safe Operating Area

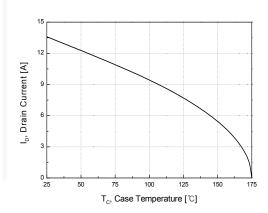


Figure 10. Maximum Drain Current vs. Case Temperature

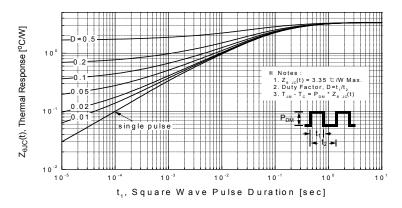


Figure 11. Transient Thermal Response Curve

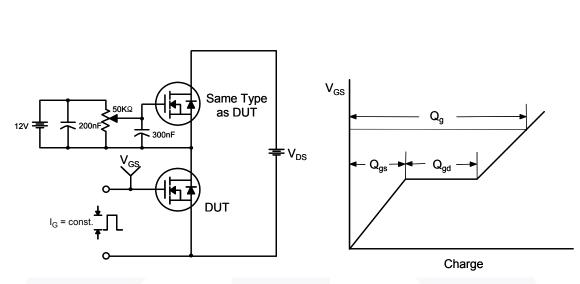


Figure 12. Gate Charge Test Circuit & Waveform

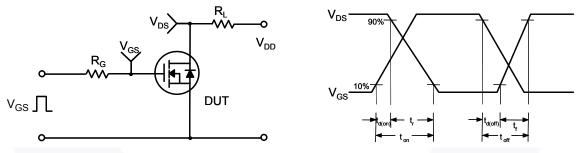


Figure 13. Resistive Switching Test Circuit & Waveforms

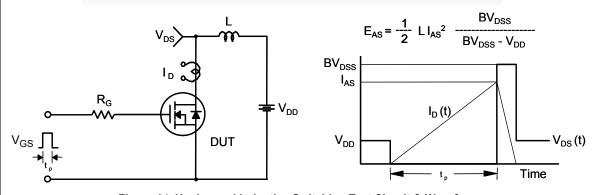
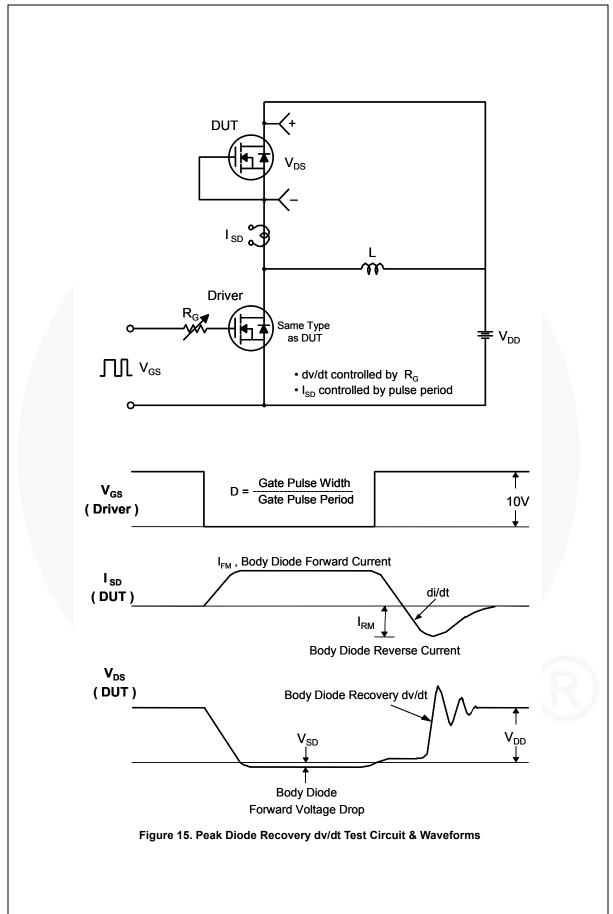


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions

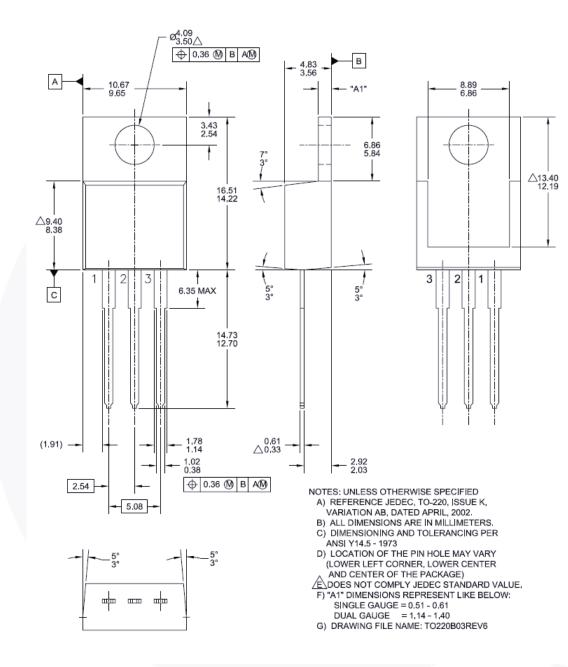


Figure 16 TO-220, Molded, 3-Lead, Jedec Variation AB

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